

Design of new material solar cell and analysis of efficiency, cost and resource availability.

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Team: SdDec24-21

URL: <https://sddec24-21.sd.ece.iastate.edu>

Our Team



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Device Fabrication



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Component Design
Device Fabrication



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Fabrication Design
Device Testing



Michael Thomas:
Fabrication Design
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Jonathan Timm:
Economic Analysis
Material Viability



Jacob Steffens:
Economic Analysis
Material Viability

Background



Problem Statement:

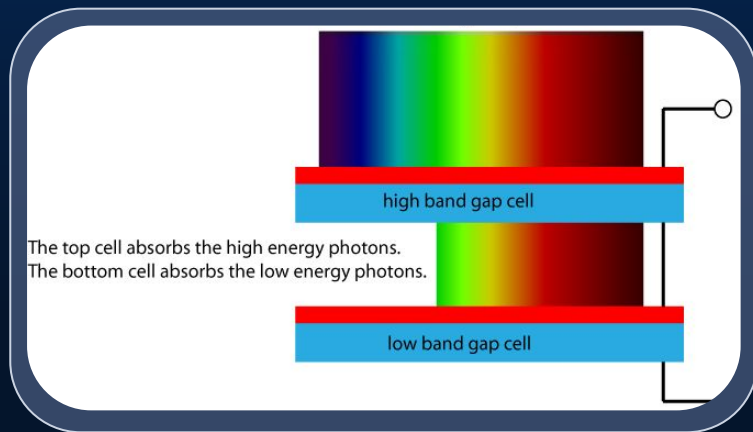
- Typical solar cells are a semiconductor made of silicon, and convert light into electricity.
- Silicon cells are approaching their theoretical efficiency limit. (~30%)



Background

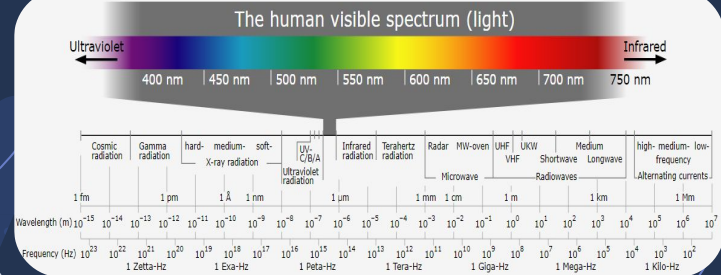
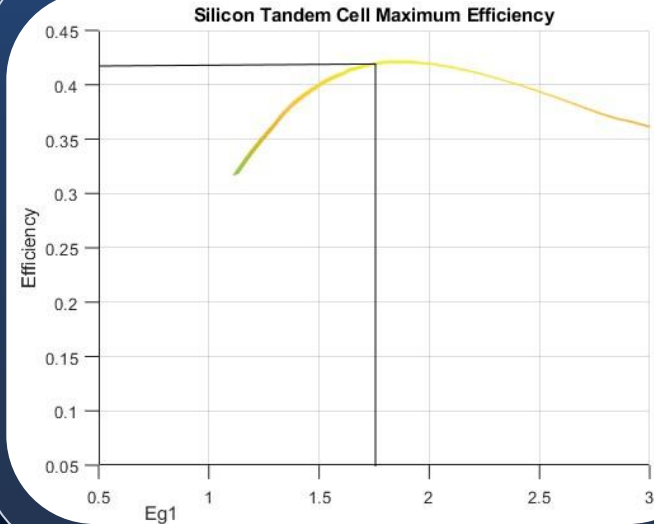
Solution:

- One way to increase commercial efficiency past this point is to add a second solar cell on top made of a different material.
- Our project is to develop a CdSe-Si tandem cell
- This would benefit a wide range of users from utility companies to local residents



Background

- Key concepts:
 - Semiconductors absorb light efficiently in certain ranges of light spectrum
 - Energy lower than the band gap will pass through the material
 - Tandem cells have an ideal band gap pairing for ideal efficiencies
- CdSe absorbs higher energy light more efficiently than Silicon.
 - Silicon | $E_g = 1.12 \text{ eV}$
 - CdSe | $E_g = 1.74 \text{ eV}$



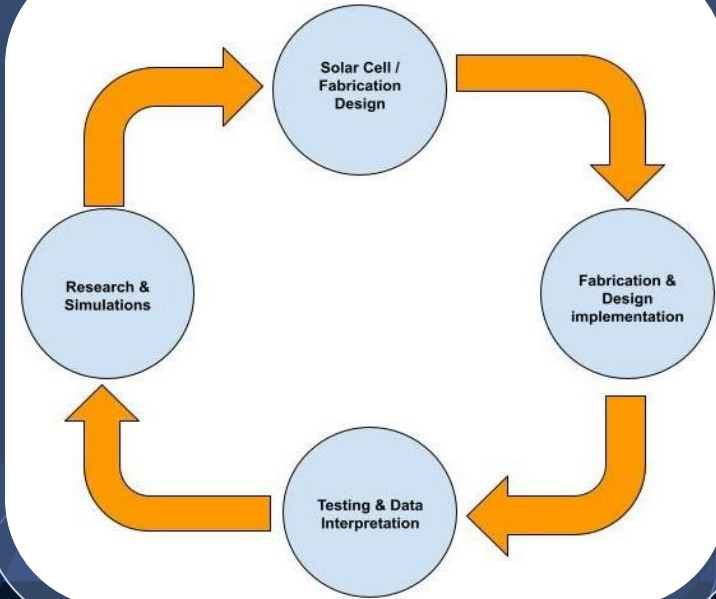
Spring Semester: (CdSe only)

1. Identify the problem (Background)
2. Potential Solutions / Semiconductor Materials (Overview)
3. Break the project down into two major parts:
 - Fabrication & Testing Process Design
 - Economic Feasibility & Environmental Viability

Fall Semester: (Silicon tandem cell introduced)

1. CdSe-Si presented a unique challenge, involving research not conducted since the 1980s
2. Required more research before fabrication could begin, as well as more total fabrication time
3. Training: Lab Safety, Fabrication, Measurement
4. Potential Silicon + Tandem Cell Solutions / Semiconductor Materials
5. Fabrication of silicon, then CdSe tandem cell
6. Economic analysis & research environmental viability
7. Reports on findings and secure fabricated cells

Iterative Design Process



Technical Requirements



- Achieve separately functioning CdSe and Si solar cells
 - Exponential I vs V curves (Large Fill Factor)
 - $V_{oc} \sim 0.5V$ for Si and $\sim 0.8V$ for CdSe
- Achieve a tandem $V_{oc} \sim 1.2V$
- Economic and sustainability analysis to assess the viability of tandem cell implementation

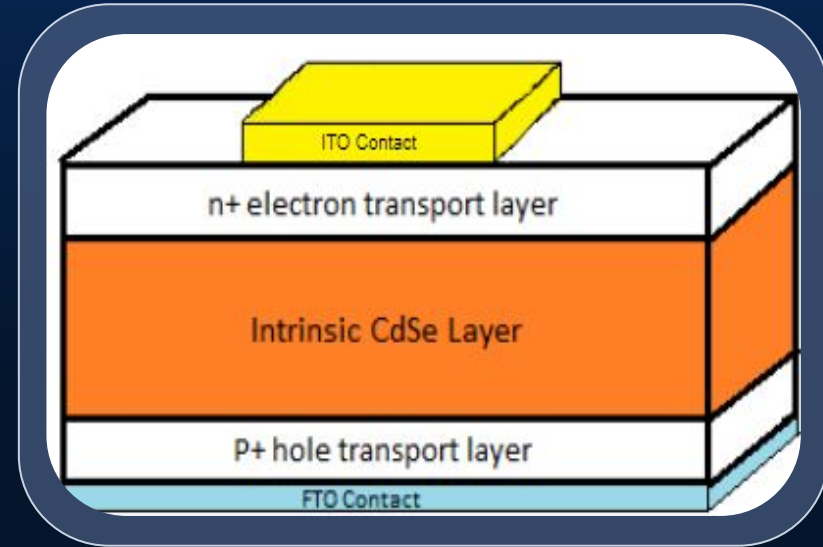
Design Overview - Cell Design and choice of materials:

In general solar cells have:

- P-N junction
- Conductive contacts

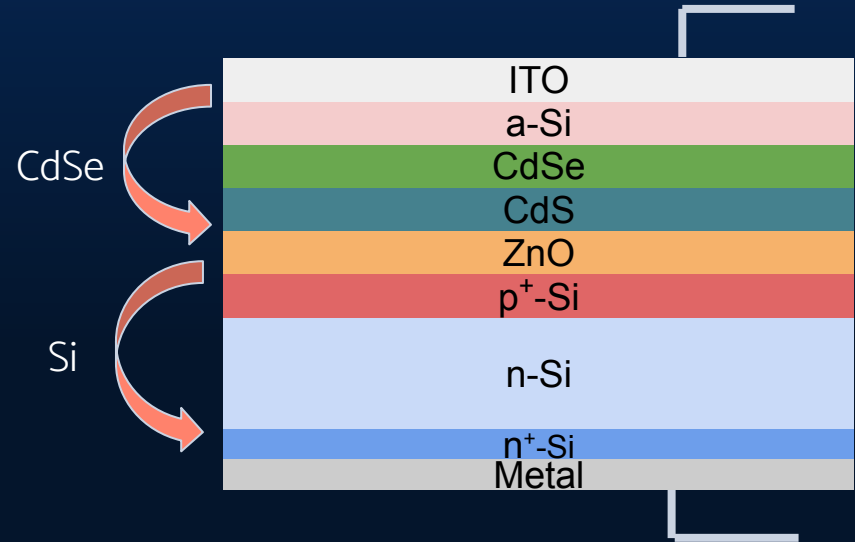
These components are carefully chosen based on material properties:

- Material Interfaces
- Relative energy levels
- Material Thickness

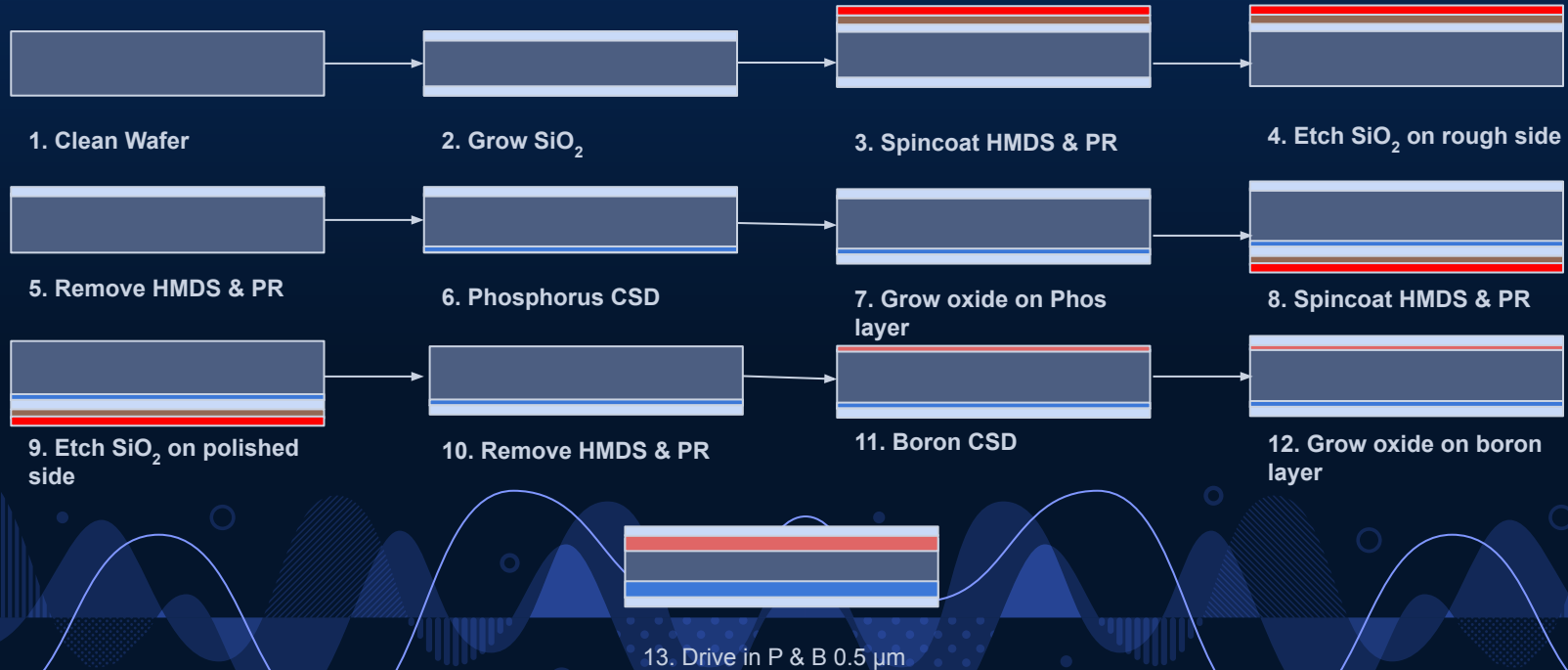


Design Overview - New Device Design

- This semester, we have switched design goals to fabricate a tandem cell rather than focusing on CdSe
- New fabrication process was developed to add the Si bottom cell



Design Overview - Silicon Cell Process



Si Wafer Cleaning



Phosphorus Doping



Boron Doping



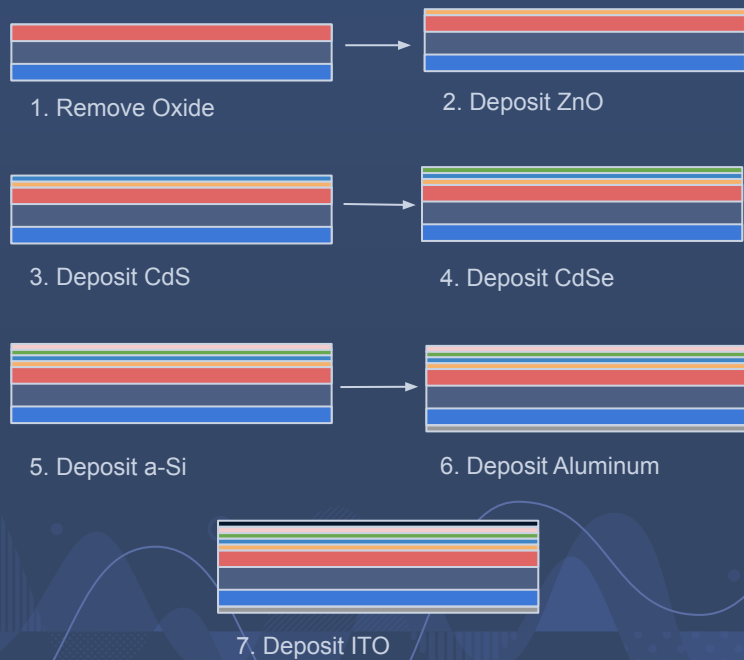
Si Cell with Al Back Contact



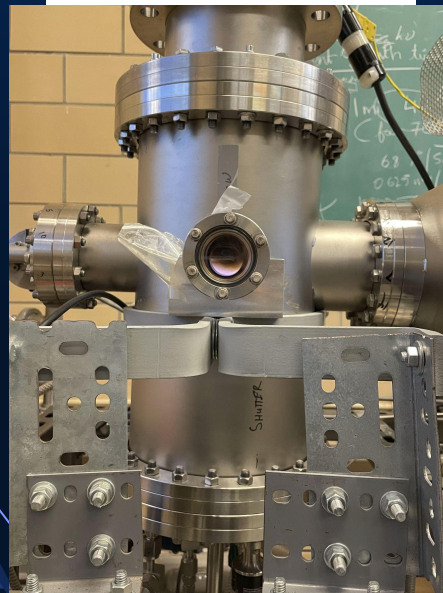
Si Cell with ZnO Top Contact



Design Overview - CdSe on Si Process



Sputtering Chamber

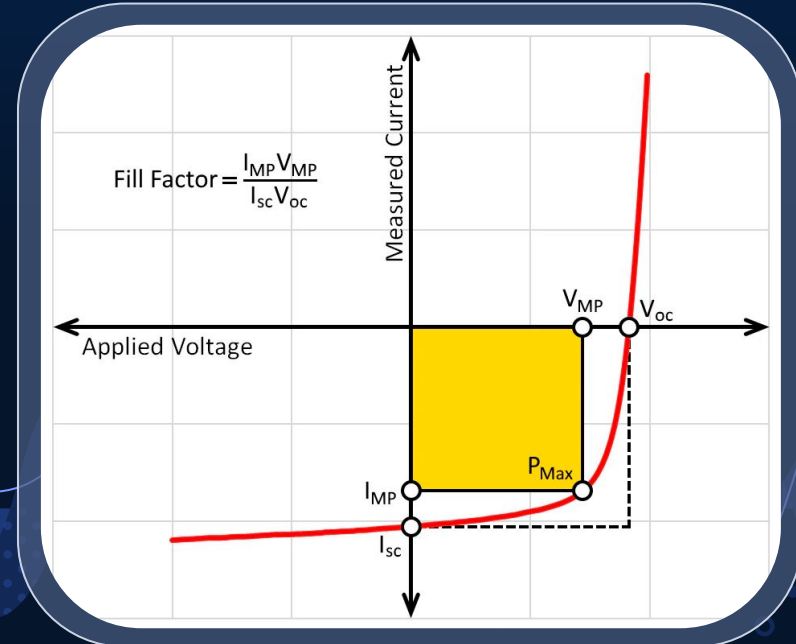
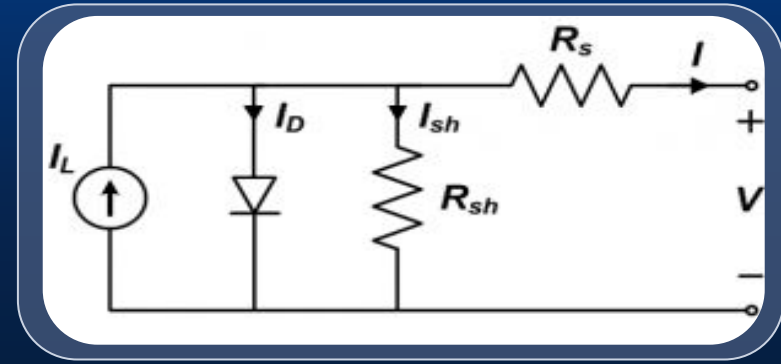


CdS/CdSe
Evaporation Chamber



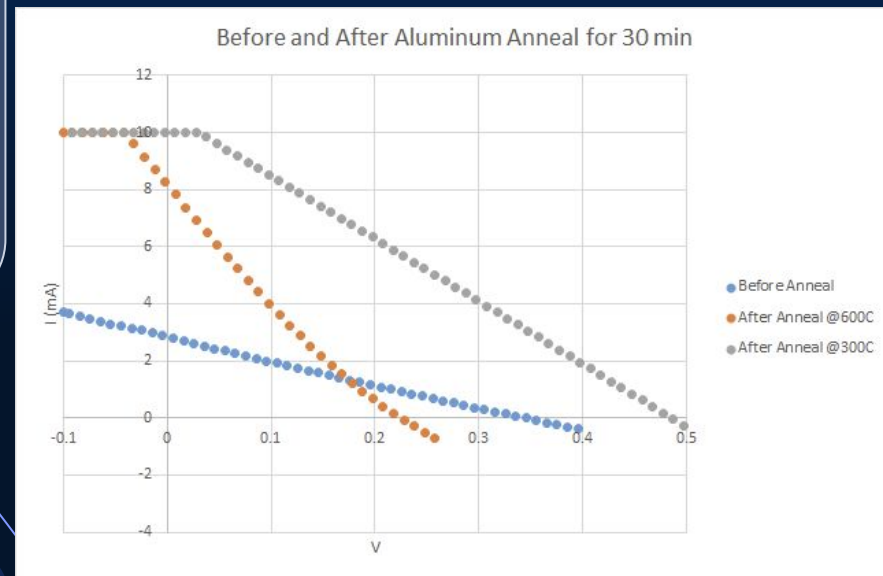
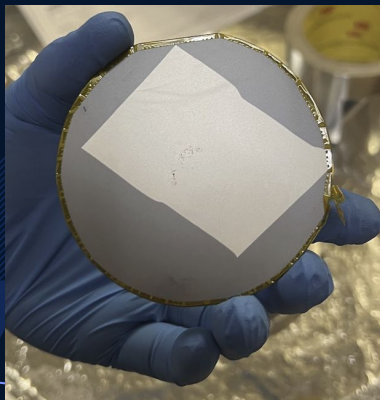
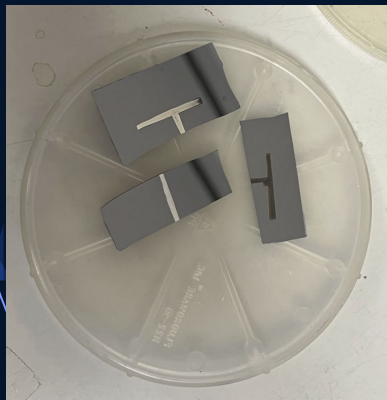
Solar Cell Model

- Circuit model helps identify where issues exist in the cell
- Measures I_{sc} & V_{oc}
- Identifies issues
 - Shunt resistance
 - Series resistance



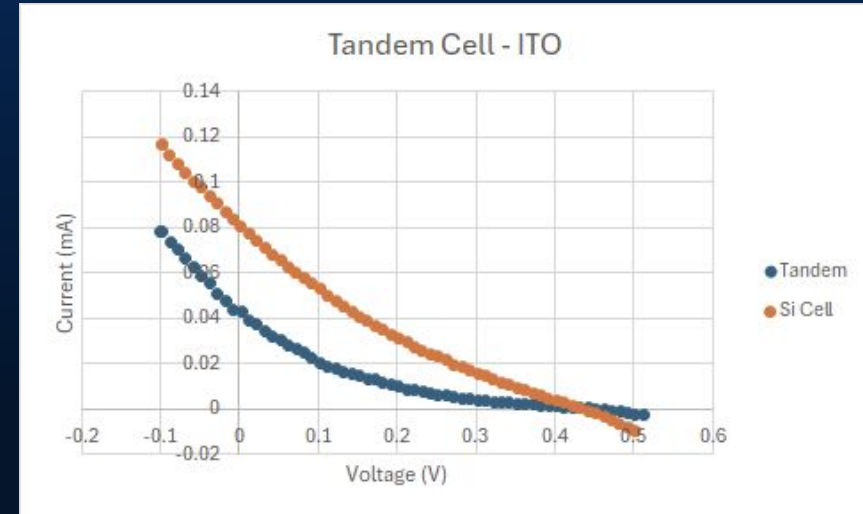
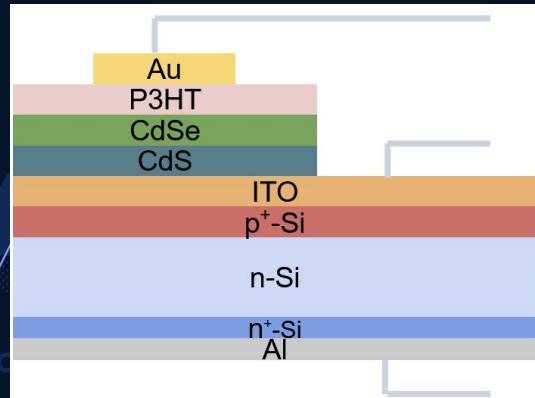
Testing Solar Cell Performance - Silicon

- One of the first experiments was with aluminum annealing temperature
 - Before anneal - $V_{OC} = .34V$
 - After 600°C - $V_{OC} = .22V$
 - After 300°C - $V_{OC} = .48V$



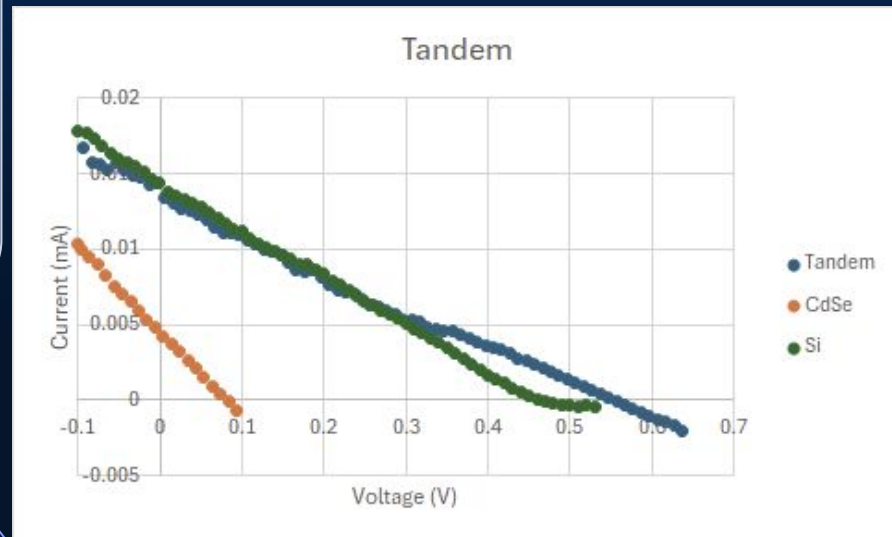
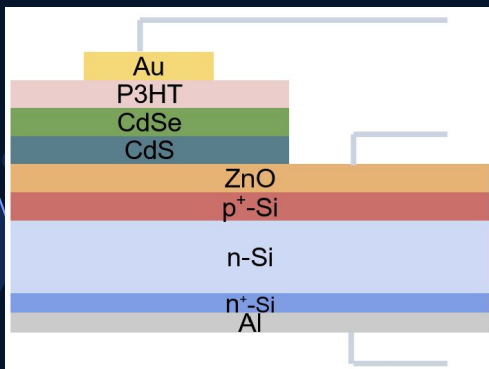
Testing Solar Cell Performance - Tandem

- The tandem cell with ITO interlayer resulted in a highly shunted CdSe cell
 - $V_{\text{CdSe}} = 0\text{V}$
- After CdSe is deposited, it is annealed at 400°C for 24 hours
 - This annealing is believed to have degraded the ITO layer



Testing Solar Cell Performance - Tandem

- Tandem cell produced $V_{OC} = .56V$
- Demonstration of a tandem solar cell with $V_{Si} + V_{CdSe} = V_{Tandem}$
- Largest loss of voltage due to low voltage of CdSe cell





$$\text{Cost Per Watt of CdSe Cell} = \$0.28/W \frac{32\%}{28\%} = \$0.32/W$$

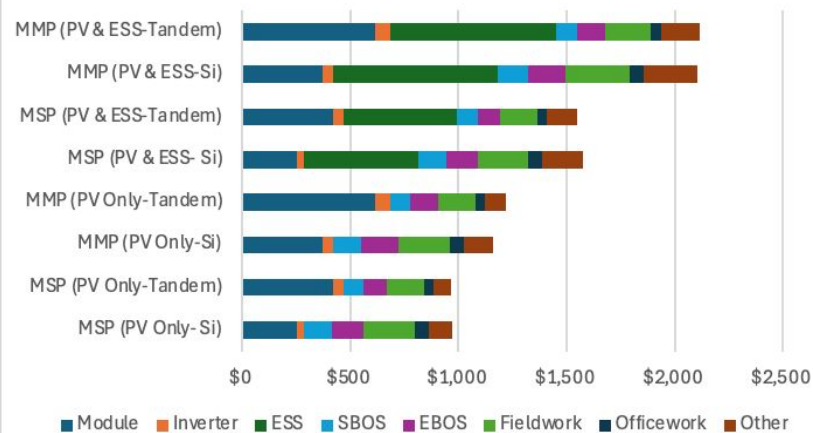
$$\text{Assumed efficiency (\%)} = \text{Max Theoretical Efficiency} \times 0.63 = 45\% \times 0.63 = 28.35\%$$

$$\text{Increase in Efficiency} = \frac{28.35\%}{20.5\%} = 1.383$$

$$\text{Cost of CdSe - Si tandem cell (\$/W)} = \frac{\$0.26/W + \$0.32/W}{1.383} = \$0.42/W$$

- Silicon slightly beats modeled market price of theoretical CdSe-Si cells and tandem cell slightly beats Si for minimum sustainable price.
- Overall, despite similar \$/W, tandem cells will still deliver more energy than Si.
- The NREL analysis didn't consider land cost, which would benefit tandem cell \$/W costs.

Utility 100 MWdc NREL Benchmark Si Costs versus
Theroetical Costs of CdSe-Si Tandem Cell in \$/kW



Summary & Future Works



- Demonstrated a Si-CdSe tandem solar cell with two cells contributing to the overall V_{OC}
- Conducted a sustainability and economic analysis of CdSe as a tandem solar cell to Si
- The goal V_{OC} of 1.2V was not achieved, but points for improvement are:
 - Fixing shunt resistance issue of Si and CdSe
 - Optimizing ZnO interlayer thickness
 - Study a-Si as the p-type heterojunction